

SOTINYTM Low Voltage Dual SPDT Analog Switch 2:1 Mux/DeMux Bus Switch

Features

· CMOS Technology for Bus and Analog Applications

Low On-Resistance: 8Ω at 3.0V
 Wide V_{CC} Range: 1.65V to 5.5V

• Rail-to-Rail Signal Range

• Control Input Overvoltage Tolerance: 5.5V min.

Fast Transition Speed: 5.2ns max. at 5V

• High Off Isolation: 57dB at 10MHz

• 54dB (10MHz) Crosstalk Rejection Reduces Signal Distortion

Break-Before-Make Switching

• High Bandwidth: 250 MHz

• Extended Industrial Temperature Range: -40°C to 85°C

• Packaging (Pb-free & Green available):

-12-contact TDFN (ZA)

Applications

· Cell Phones

PDAs

• Portable Instrumentation

• Battery Powered Communications

Computer Peripherals

Pin Description

Pin Number	Name	Description		
8, 11	$_1B_X$	Data port (Normally Open)		
3, 6	GND	Ground		
2, 5	$_0$ B $_{ m X}$	Data port (Normally Closed)		
1, 4	A_{X}	Common Output/data port		
9, 12	V _{CC}	Positive Power Supple		
7, 10	S_X	Logic Controll		

Notes:

1. x = 0 or 1

Logic Function Table

Logic Input(s)	Function
0	₀ B _X Connection to A _X
1	₁ B _X Connected to A _X

Description

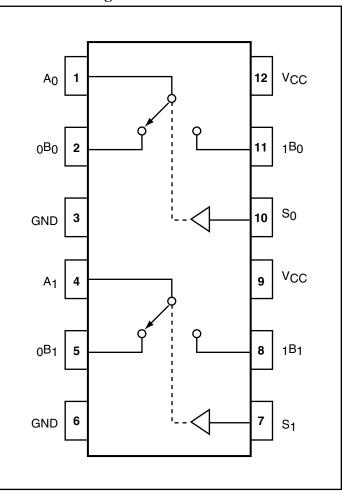
The PI5A3158 is a dual high-bandwidth, fast single-pole double-throw (SPDT) CMOS switch. It can be used as an analog switch or as a low-delay bus switch. Specified over a wide operating power supply voltage range, 1.65V to 5.5V, the PI5A3158 has a maximum On-Resistance of 12Ω at 1.65V, 9Ω at 2.3V & 6Ω at 4.5V.

Break-before-make switching prevents both switches being enabled simultaneously. This eliminates signal disruption during switching.

The control input, S, tolerates input drive signals up to 5.5V, independent of supply voltage.

Connection Diagram

1





Absolute Maximum Ratings(1)

Supply Voltage V _{CC}	
DC Switch Voltage (V _S) ⁽²⁾	-0.5V to V _{CC} $+0.5$ V
DC Input Voltage (V _{IN}) ⁽²⁾	0.5V to +7.0V
DC Output Current (V _{OUT})	128mA
DC V _{CC} or Ground Current (I _{CC} /I _{GND})	$\pm 100 mA$
Storage Temperature Range (T _{STG})	65°C to +150°C
Junction Temperature under Bias (T _J)	150°C
Junction Lead Temperature (T _L)	
(Soldering, 10 seconds)	260°C
Power Dissipation (P _D) @ +85°C	180mW

Recommended Operating Conditions(3)

Supply Voltage Operating (V _{CC}) 1.65V to 5.5V
Control Input Voltage (V_{IN}) 0V to V_{CC}
Switch Input Voltage (V _{IN}) 0V to V _{CC}
Output Voltage (V _{OUT}) 0V to V _{CC}
Operating Temperature (T _A)40°C to +85°C
Input Rise and Fall Time (t_r, t_f)
Control Input $V_{CC} = 2.3V - 3.6V \dots 0ns/V$ to $10ns/V$
Control Input $V_{CC} = 4.5V - 5.5V$
Thermal Resistance (θ_{JA})

Notes:

- 1. Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.
- 2. The input and output negative voltage ratings may be exceeded if the inut and output diode current ratings are observed.
- 3. Control input must be held HIGH or LOW; it must not float.

DC Electrical Characteristics (Over the Operating temperature range, $T_A = -40$ °C to 85°C)

Parameters	Description	Test Conditions	Supply Voltage	Тетр	Min.	Тур.	Max.	Units
V_{IAR}	Analog Input Signal Range		V _{CC}	$T_A = 25^{\circ}\text{C \&}$ -40°C to 85°C	0		V_{CC}	V
		$I_{O} = 30 \text{mA}, V_{IN} = 0 \text{V}$				4	6	
R_{ON}		$I_O = -30 \text{mA}, V_{IN} = 2.4 \text{V}$	4.5V	$T_A = 25^{\circ}C$		5	8	
		$I_O = -30 \text{mA}, V_{IN} = 4.5 \text{V}$				8	13	
		$I_{O} = 30 \text{mA}, V_{IN} = 0 \text{V}$		T. 400G			6	
R_{ON}		$I_O = -30 \text{mA}, V_{IN} = 2.4 \text{V}$	4.5V	$T_A = -40$ °C to 85 °C			8	Ω
		$I_O = -30 \text{mA}, V_{IN} = 4.5 \text{V}$					13	
D	On- Resistance ⁽⁴⁾	$I_{O} = 24 \text{mA}, V_{IN} = 0 \text{V}$	3.0V	$T_A = 25$ °C		5	8	
R_{ON}		$I_O = -24 \text{mA}, V_{IN} = 3.0 \text{V}$				12	19	
D		$I_{O} = 24 \text{mA}, V_{IN} = 0 \text{V}$	3.0V	$T_A = -40$ °C to 85°C			8	
R_{ON}		$I_O = -24 \text{mA}, V_{IN} = 3.0 \text{V}$					19	
D		$I_{O} = 24 \text{mA}, V_{IN} = 0 \text{V}$	2.237	$T_A = 25$ °C		6	9	
R_{ON}		$I_{O} = -24 \text{mA}, V_{IN} = 2.3 \text{V}$	2.3V			16	24	
D		$I_{O} = 24 \text{mA}, V_{IN} = 0 \text{V}$	2.3V	$T_A = -40$ °C to 85°C			9	
R_{ON}		$I_{O} = -24 \text{mA}, V_{IN} = 2.4 \text{V}$	2.3 V				24	
D		$I_{O} = 24 \text{mA}, V_{IN} = 0 \text{V}$	1.65V	т – 259С		8	12	
R_{ON}		$I_{O} = -24$ mA, $V_{IN} = 1.65$ V		$T_A = 25$ °C		27	39	
D		$I_{O} = 24 \text{mA}, V_{IN} = 0 \text{V}$	1.6537	$T_A = -40$ °C to 85°C			12	
R_{ON}		$I_{O} = -24$ mA, $V_{IN} = 1.65$ V	1.65V				39	

2



DC Electrical Characteristics (Over the Operating temperature range, $T_A = -40$ °C to 85°C) (continued)

Parameters	Description	Test Conditions	Supply Voltage	Temp	Min.	Тур.	Max.	Units
		$I_A = -30 \text{mA}, V_{BN} = 3.15 \text{V}$	4.5V			0.15		
A.D	On-Resistance Match Between	$I_A = -24 \text{mA}, V_{BN} = 2.1 \text{V}$	3.0V	$T_A = 25$ °C		0.2		
ΔR_{ON}	Channels ^(4, 5, 6)	$I_A = -8mA, V_{BN} = 1.6V$	2.3V	$\int_{A} I_{A} = 23 \text{ C}$		0.3		
		$I_A = -4mA, V_{BN} = 1.15V$	1.65V			0.3		Ω
		$I_A = -30 \text{mA}, \ 0 \le V_{BN} \le V_{CC}$	5.0V			6		1 22
D	On-Resistance	$I_A = -24 \text{mA}, \ 0 \le V_{BN} \le V_{CC}$	3.3V	T 250C		12		
R _{ONF}	Flatness ^(4, 5, 7)	$I_A = -8mA$, $0 \le V_{BN} \le V_{CC}$	2.5V	$T_A = 25$ °C		22		
		$I_A = -4mA$, $0 \le V_{BN} \le V_{CC}$	1.8V			90		
			$V_{CC} = 1.65 V \text{ to}$		0.75			
$V_{ m IH}$	Input High Voltage	Logic High Level	1.95V	$T_{A} = -40^{\circ}C$	V_{CC}			
			$V_{CC} = 2.3 \text{V to}$ 5.5 V	to 85°C	0.7 V _{CC}			
	Input Low Voltage	LLOGIC LOWLEVEL	$V_{CC} = 1.65V \text{ to}$ 1.95V					V
V_{IL}			$V_{CC} = 2.3 \text{V to}$ 5.5 V					
	Innut I calcago			$T_A = 25$ °C			±0.1	
Input Leakage Curent		$0 \le V_{IN} \le 5.5V$	$V_{\rm CC} \le 0V \le 5.5V$	$T_A = -40$ °C to 85°C			±1.0	
	OFF State		V = = < 1.65V <	$T_A = 25$ °C			±0.1	
$I_{ m OFF}$	Leakage Cur- rent	ge Cur- $0 \le V_{\rm IN} \le 5.5 V$	$V_{CC} \le 1.65 V \le 5.5 V$	$T_A = -40$ °C to 85°C			±10	μА
	Oning a ant State	All Channels ON or OFF,		$T_A = 25$ °C			2	
I _{CC}	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND, I_{OUT} = 0	$V_{CC} = 5.5V$	$T_A = -40$ °C to 85°C			20	

Notes:

- 4. Measured by voltage drop between A and B pins at the indicated current through the device. On-Resistance is determined by the lower of the voltages on two ports (A or B).
- 5. Parameter is characterized but not tested in production.
- 6. $\Delta R_{ON} = R_{ON} \text{ max} R_{ON} \text{ min.}$ measured at identical V_{CC} , temperature and voltage levels.
- 7. Flatness is defined as difference between maximum and minimum value of On-Resistance over the specified range of conditions.
- 8. Guaranteed by design.

Capacitance⁽¹²⁾

Parameters	Description Test Condi		Supply Voltage	Temp	Min.	Тур.	Max.	Units
C_{IN}	Controll Input					2.3		
C _{IO-B}	For B Port, Switch OFF	$f = 1 \text{ MHz}^{(12)}$	$V_{CC} = 5.0V$	$T_A = 25$ °C		6.5		pF
C _{IOA-ON}	For A Port, Switch ON	I = I MIHZ				18.5		

3



Switch and AC Characteristics

Parameters	Description	Test Conditions	Supply Voltage	Temp	Min.	Тур.	Max.	Units
	See tes	See test circut	$V_{CC} = 2.3 \text{V to } 2.7 \text{V}$	T. 250G.0		1.2		
t _{PLH} t _{PHL}	Propagation Delay: A to Bn	diagram 1 and 2	$V_{CC} = 3.0 \text{V to } 3.6 \text{V}$	$T_A = 25^{\circ}C \& -40^{\circ}C \text{ to } 85^{\circ}C$		0.8		
ЧHL	Delay. A to Bil	V _I Open ⁽¹⁰⁾	$V_{CC} = 4.5 \text{V to } 5.5 \text{V}$	-40 € 10 63 €		0.3		
		See test circut	$V_{CC} = 1.65 V \text{ to } 1.95 V$		7		23	
$t_{ m PZL}$	Output Enable Turn ON Time:	diagram 1 and 2 $V_I = 2 V_{CC}$ for	$V_{CC} = 2.3 \text{V to } 2.7 \text{V}$	$T_{A} = 25^{\circ}C$	3.5		13	
t_{PZH}	A to Bn	t_{PZL} , $V_I = 0V$ for	$V_{CC} = 3.0 \text{V to } 3.6 \text{V}$	1 _A – 23 C	2.5		6.9	
		t _{PZH}	$V_{CC} = 4.5 \text{V to } 5.5 \text{V}$		1.7		5.2	
		See test circut	$V_{CC} = 2.5V$				24	
$t_{ m PZL}$	Output Enable Turn ON Time:	diagram 1 and 2 $V_I = 2 V_{CC}$ for	$V_{CC} = 3.3V$	$T_A = 25^{\circ}C \&$			14	
t_{PZH}	A to Bn	t_{PZL} , $V_I = 0V$ for	$V_{CC} = 3.0 \text{V to } 3.6 \text{V}$	-40°C to 85°C			7.6	
		t _{PZH}	$V_{CC} = 4.5 \text{V to } 5.5 \text{V}$				5.7	
		See test circut	$V_{CC} = 1.65V \text{ to } 1.95V$		3		12.5	
$t_{\rm PLZ}$	Output Disable-	diagram 1 and 2	$V_{CC} = 2.3 \text{V to } 2.7 \text{V}$	$T_A = 25^{\circ}C$	2		7	
$t_{ m PHZ}$	Turn OFF Time: A to Bn	$\begin{aligned} V_I &= 2 \ V_{CC} \ \text{for} \\ t_{PZL}, \ V_I &= 0V \ \text{for} \\ t_{PZH} \end{aligned}$	$V_{CC} = 3.0 \text{V to } 3.6 \text{V}$		1.5		5	
			$V_{CC} = 4.5 \text{V to } 5.5 \text{V}$		0.8		3.5	
		See test circut	$V_{CC} = 2.5V$	T _A = 25°C & -40°C to 85°C			13	
$t_{\rm PLZ}$	Output Disable- Turn OFF Time: A to Bn		$V_{CC} = 3.3V$				7.5	
t_{PHZ}			$V_{CC} = 3.0 \text{V to } 3.6 \text{V}$				5.3	
			$V_{CC} = 4.5 \text{V to } 5.5 \text{V}$				3.8	
			$V_{CC} = 2.5V$	T _A = 25°C & -40°C to 85°C	0.5			
4		(0)	$V_{CC} = 3.3V$		0.5			
ιBW			$V_{CC} = 3.0 \text{V to } 3.6 \text{V}$		0.5			
			$V_{CC} = 4.5 \text{V to } 5.5 \text{V}$		0.5			
		$C_{L} = 0.1 \text{nF},$	$V_{CC} = 5.0V$			7		
Q	Charge Injection	$V_{GEN} = 0V,$ $R_{GEN} = 0\Omega,$ See test circut 4	$V_{CC} = 3.3V$	$T_A = 25$ °C		3		рC
O _{IRR}	Off Isolation	$R_L = 50\Omega,$ $V_{GEN} = 0V,$ $R_{GEN} = 0\Omega,$ See test circut 5 ⁽¹¹⁾	$V_{CC} = 1.65 \text{V to } 5.5 \text{V}$	$T_A = 25$ °C		-57		dB
X_{TALK}	Crosstalk Isolation	See test circut 6	$V_{CC} = 1.65 \text{V to } 5.5 \text{V}$	$T_A = 25$ °C		-54		
f_{3dB}	-3dB Bandwidth	See test circut 9	$V_{CC} = 1.65 \text{V to } 5.5 \text{V}$	$T_A = 25$ °C		250		MHz

Notes:

- 9. Guaranteed by design.
- 10. Guaranteed by design but not production tested. The device contributes no other propagation delay other than the RC delay of the switch On-Resistance and the 50pF load capacitance, whine driven by an ideal voltage source with zero output impedance.

4

- 11. Off Isolation = 20 Log₁₀ [V_A / V_{Bn}] and is measured in dB.
- 12. $T_A = 25$ °C, f = 1MHz. Capacitance is characterized but not tested in production.



Test Circuits and Timing Diagrams

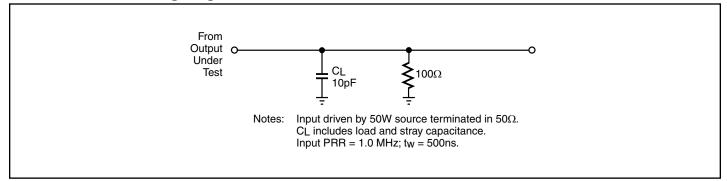


Figure 1. AC Test Circuit

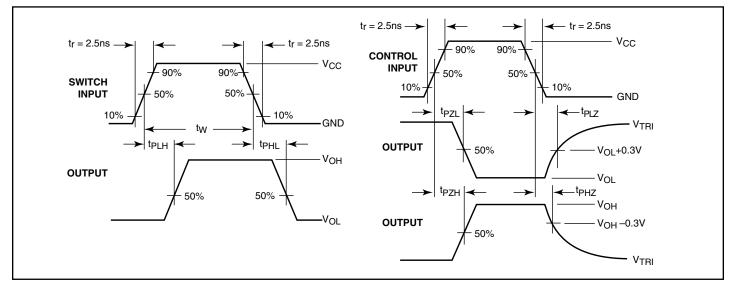


Figure 2. AC Waveforms

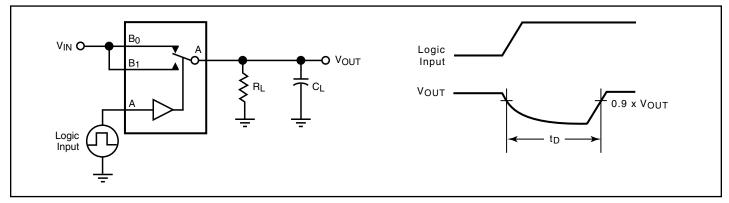


Figure 3. Break Before Make Interval Timing

5

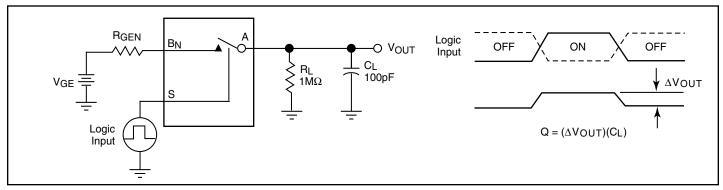


Figure 4. Charge Injection Test

6

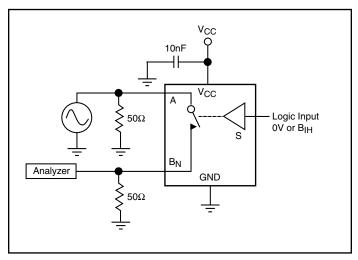


Figure 5. Off Isolation

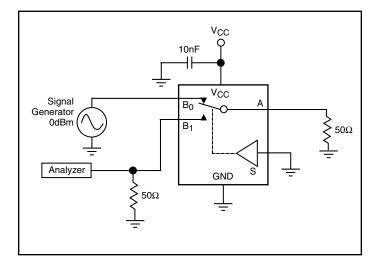


Figure 6. Crosstalk

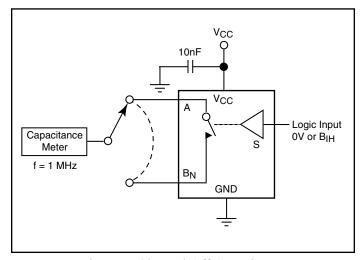


Figure 7. Channel Off Capacitance

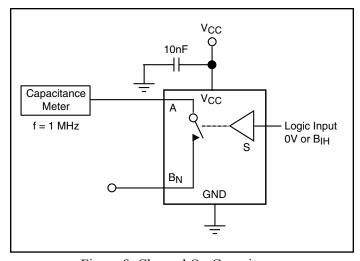


Figure 8. Channel On Capacitance



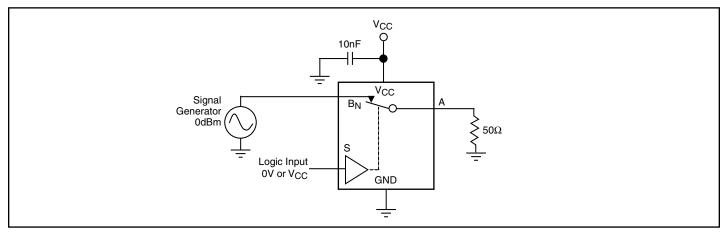
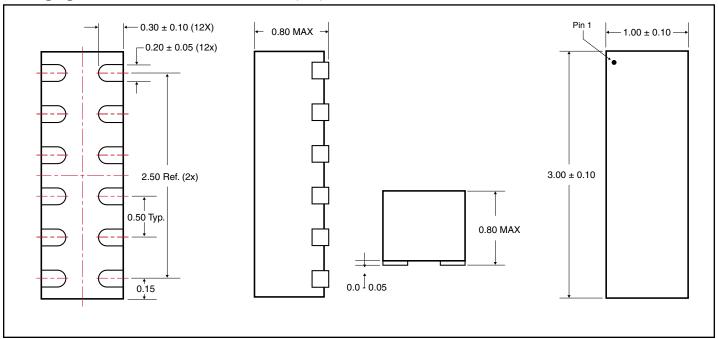


Figure 9. Bandwidth

Packaging Mechanical: 12-contact TDFN (ZA)



Ordering Information

Ordering Code	Packaging Code	Package Type
PI5A3158ZA ⁽¹⁾	ZA	12-contact TDFN
PI5A3158ZAE	ZA	Pb-free & Green, 12-contact TDFN

Notes:

- This product has always shipped as only a lead free product, but since it was introduced prior to Pericom's strategy of adding an E to all Green/ Lead free parts many customers order it without the E suffix. Please migrate new designs and qualification to include the E suffix. Pericom at this point in time will continue to offer devices marked both ways, but may at a later date eliminate the non-E part number.
- Thermal characteristics can be found on the company web site at www.pericom.com/packaging/

PS8637B

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